## General purpose transistor (isolated transistor and diode)

## US5L10

A 2SD2674 and a RB461F are housed independently in a TUMT5 package.

## -Applications

DC / DC converter
Motor driver

## - Features

1) $\operatorname{Tr}:$ Low $V$ ce(sat)

Di : Low $\mathrm{V}_{\mathrm{F}}$
2) Small package

## - Structure

Silicon epitaxial planar transistor
Schottky barrier diode
-External dimensions (Unit : mm)


ROHM:TUMT5 Abbreviated symbol:L10
$\bullet$ Equivalent circuit

$\bullet$ Packaging specification s

| Type | US5L10 |
| :---: | :---: |
| Package | TUMT5 |
| Marking | L10 |
| Code | TR |
| Basic ordering unit(pieces) | 3000 |

## Transistors

## -Absolute maximum ratings $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

Tr1

| Parameter | Symbol | Limits | Unit |
| :--- | :---: | :---: | :---: |
| Collector-base voltage | $\mathrm{V}_{\text {CBO }}$ | 15 | V |
| Collector-emitter voltage | $\mathrm{V}_{\text {CEO }}$ | 12 | V |
| Emitter-base voltage | $\mathrm{V}_{\text {EBO }}$ | 6 | V |
| Collector current | IC | 1.5 | A |
|  | ICP | 3 | A |
| Power dissipation | PC | 0.9 | $\mathrm{~W} /$ ELEMENT $^{* 2}$ |
| Junction temperature | Tj | 150 | ${ }^{\circ} \mathrm{C}$ |
| Range of storage temperature | Tstg | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |

$* 2$ Mounted on a $25 \mathrm{~mm} \times 25 \mathrm{~mm} \times{ }^{\mathrm{t}} 0.8 \mathrm{~mm}$ ceramic substrate

| Di2 |  |  |  |
| :---: | :---: | :---: | :---: |
| Parameter | Symbol | Limits | Unit |
| Average rectified forward current | IF | 700 | mA |
| Forward current surge peak ( $60 \mathrm{~Hz}, 1 \infty$ ) | IFSM | 3 | A |
| Reverse voltage (DC) | VR | 20 | V |
| Junction temperature | Tj | 125 | ${ }^{\circ} \mathrm{C}$ |
| Range of storage temperature | Tstg | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Peak reverse voltage | VRM | 25 | V |
| Power dissipation | PD | 0.5 | W/ELEMENT |

* Mounted on a $25 \mathrm{~mm} \times 25 \mathrm{~mm} \times{ }^{\mathrm{t}} 0.8 \mathrm{~mm}$ ceramic substrate

Tr1\& Di2

| Parameter | Symbol | Limits | Unit |
| :--- | :---: | :---: | :---: |
| Total power dissipation | PD | 0.4 | W/TOTAL |
|  |  | 1.0 | W/TOTAL $* 2$ |
| *1 Each terminal mounted on a recommended land <br> $* 2$ Mounted on a $25 m m \times 25 \mathrm{~mm} \times{ }^{+} 0.8 \mathrm{~mm}$ ceramic substrate |  |  |

- Electrical characteristics $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

Tr1

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Collector-base breakdown voltage | BV сво | 15 | - | - | V | $\mathrm{lc}=10 \mu \mathrm{~A}$ |
| Collector-emitter breakdown voltage | BV'eo | 12 | - | - | V | $\mathrm{lc}=1 \mathrm{~mA}$ |
| Emitter-base breakdown voltage | BV ebo $^{\text {a }}$ | 6 | - | - | V | $\mathrm{l}=10 \mu \mathrm{~A}$ |
| Collector cutoff current | Icbo | - | - | 100 | nA | $\mathrm{V}_{\mathrm{CB}}=15 \mathrm{~V}$ |
| Emitter cutoff current | Iebo | - | - | 100 | nA | $\mathrm{V}_{\text {eb }}=6 \mathrm{~V}$ |
| Collector-emitter saturation voltage | VCE(sat) | - | 85 | 200 | mV | $\mathrm{IC} / \mathrm{lg}=500 \mathrm{~mA} / 25 \mathrm{~mA}$ |
| DC current gain | hfe | 270 | - | 680 | - | V cE/ $/ \mathrm{c}=2 \mathrm{~V} / 200 \mathrm{~mA}$ |
| Transition frequency | ${ }_{\text {ft }}$ | - | 400 | - | MHz | $\mathrm{V}_{\text {ce }}=2 \mathrm{~V}, \mathrm{le}=-200 \mathrm{~mA}, \mathrm{f}=100 \mathrm{MHz}$ * |
| Collector output capacitance | Cob | - | 12 | - | pF | $\mathrm{V}_{\mathrm{cb}}=10 \mathrm{~V}, \mathrm{l}=0 \mathrm{~A}, \mathrm{f}=1 \mathrm{MHz}$ |

* Pulsed

Di2

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
| :--- | :---: | :---: | :---: | :---: | :---: | :--- |
| Forward voltage | $\mathrm{V}_{\mathrm{F}}$ | - | 450 | 490 | mV | $\mathrm{I}_{\mathrm{F}=700 \mathrm{~mA}}$ |
| Reverse current | $\mathrm{I}_{\mathrm{R}}$ | - | - | 200 | $\mu \mathrm{~A}$ | $\mathrm{~V}_{\mathrm{R}=20 \mathrm{~V}}$ |
| Reverse recovery time | trr | - | 9 | - | ns | $\mathrm{I}_{\mathrm{F}=\mathrm{IR}=100 \mathrm{~mA}, \mathrm{Irr}=0.1 \mathrm{IR}}$ |

## - Electrical characteristic curves



Fig. 1 DC current gain vs. collector current


Fig. 2 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current


Fig. 3 Collector-emitter saturation voltage vs. collector current


Fig. 4 Grounded emitter propagation characteristics


Fig. 5 Gain bandwidth product vs. emitter current


Fig. 6 Switching time


Transistors


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